

VS-30CTQ...S-M3

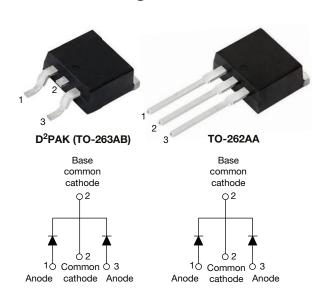
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Vishay Semiconductors

HALOGEN

FREE

High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V_{R}	80 V, 100 V					
V _F at I _F	0.67 V					
I _{RM}	7.0 mA at 125 °C					
T _J max.	175 °C					
E _{AS}	7.5 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

VS-30CTQ...-1-M3

FEATURES

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	30	А					
V _{RRM}		80/100	V					
I _{FSM}	t _p = 5 µs sine	850	А					
V _F	15 A _{pk} , T _J = 125 °C (per leg)	0.67	V					
T _J	Range	-55 to +175	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-30CTQ080S-M3 VS-30CTQ080-1-M3	VS-30CTQ100S-M3 VS-30CTQ100-1-M3	UNITS			
Maximum DC reverse voltage	V_{R}	80	100	V			
Maximum working peak reverse voltage	V_{RWM}	00	100	V			



VS-30CTQ...S-M3, VS-30CTQ...-1-M3 Series

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ABSOLUTE MAXIMUM RATINGS									
PARAMETER	PARAMETER		TEST COND	ITIONS	VALUES	UNITS			
Maximum average	per device				30				
forward current See fig. 5	per leg	I _{F(AV)}	50 % duty cycle at T _C = 129 °C	15	A				
Maximum peak one cycle	non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load	850	A			
surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	275				
Non-repetitive avalanche energy per leg		E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.50 \text{A}, L = 60 \text{mH}$		7.50	mJ			
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.50	Α			

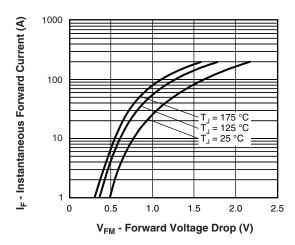
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		15 A	T _{.1} = 25 °C	0.86				
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	30 A	11 = 25 0	1.05	V			
		15 A	T _J = 125 °C	0.67				
		30 A	1J = 125 C	0.82				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V Detect V	0.55	A			
See fig. 2	IRM (")	T _J = 125 °C	V _R = Rated V _R	7.0	mA			
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		500	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 r	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R					

Note

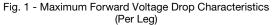
 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHAN	THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	e	T _J , T _{Stg}		-55 to 175	°C				
Maximum thermal resistance, junction to case per leg		В	DC operation	3.25	°C/W				
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.63					
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50					
Approximate weight				2	g				
Approximate weight				0.07	OZ.				
May arting toway	minimum			6 (5)	kgf · cm				
Mounting torque maximum				12 (10)	(lbf \cdot in)				
Marking device			Case style D ² PAK (TO-263AB)	30CTC 30CTC					
			Case style TO-262AA	30CTQ080-1 30CTQ100-1					

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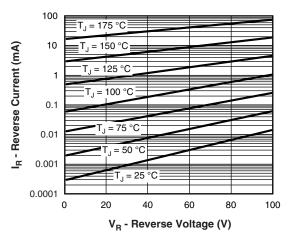


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

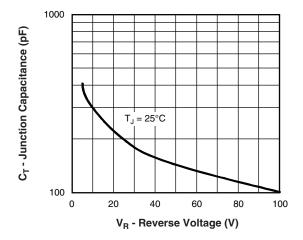


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

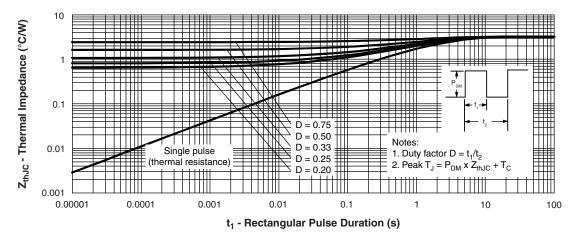


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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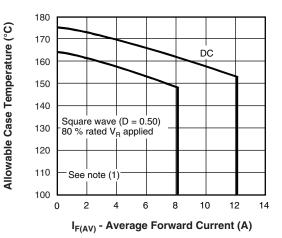


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

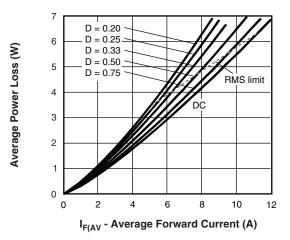


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

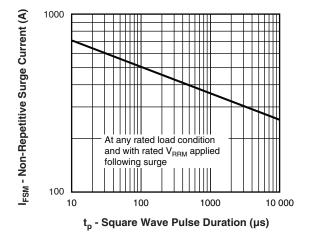


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

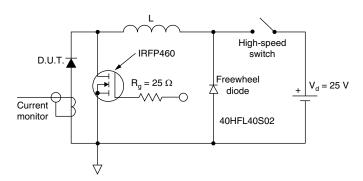


Fig. 8 - Unclamped Inductive Test Circuit

Note

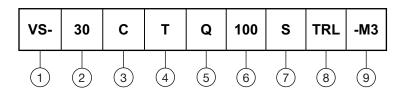
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; I_R \text{ at } V_{R1} = 10 \text{ V}. \end{array}$

VS-30CTQ...S-M3, VS-30CTQ...-1-M3 Series

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 A)

3 - Circuit configuration: C = common cathode

4 - T = TO-220

Schottky "Q" series

080 = 80 V 100 = 100 V

7 - • S = D^2PAK (TO-263AB)

• -1 = TO-262AA

8 - • None = tube

• TRL = tape and reel (left oriented - for D2PAK (TO-263AB) only)

• TRR = tape and reel (right oriented - for D²PAK (TO-263AB) only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-30CTQ080S-M3	50	Antistatic plastic tubes
VS-30CTQ080STRL-M3	800	13" diameter plastic tape and reel
VS-30CTQ080STRR-M3	800	13" diameter plastic tape and reel
VS-30CTQ100S-M3	50	Antistatic plastic tubes
VS-30CTQ100STRL-M3	800	13" diameter plastic tape and reel
VS-30CTQ100STRR-M3	800	13" diameter plastic tape and reel
VS-30CTQ080-1-M3	50	Antistatic plastic tubes
VS-30CTQ100-1-M3	50	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164				
Differisions	TO-262AA	www.vishay.com/doc?96165				
Dout moulting information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOIES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

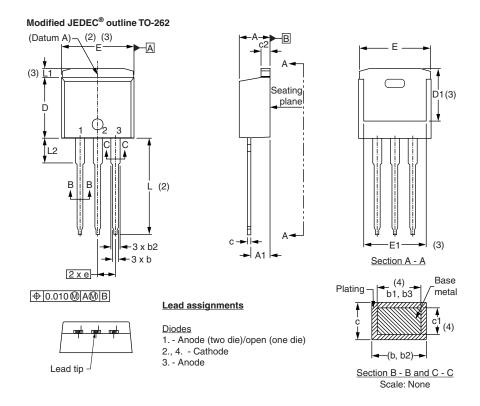
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	D BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.36	3.71	0.132	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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